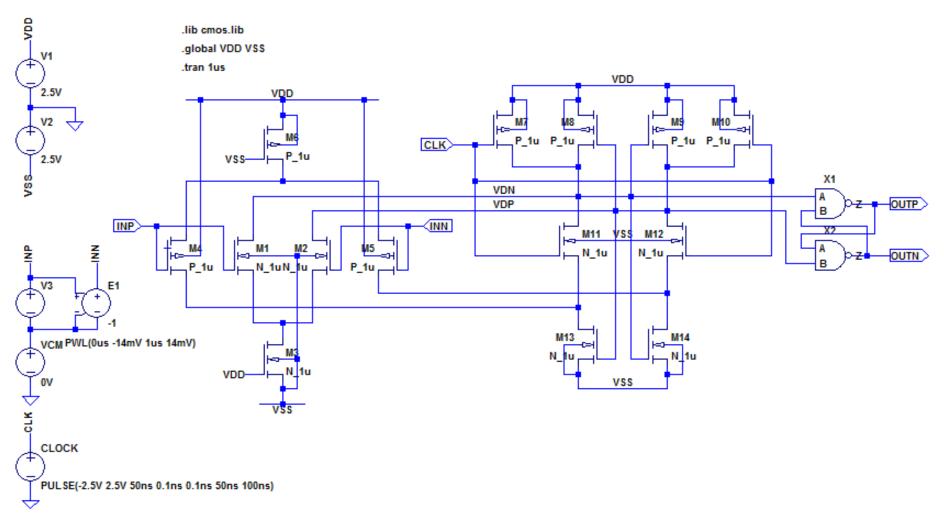
Lab. 15

## CHARACTERIZATION OF CLOCKED COMPARATOR

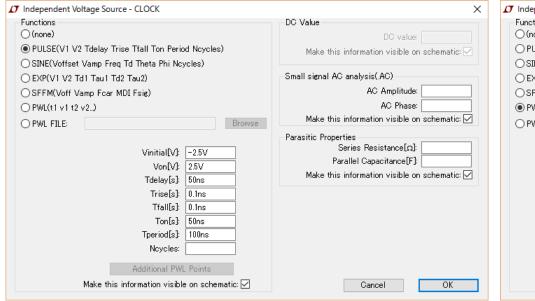
#### 1. Characterization

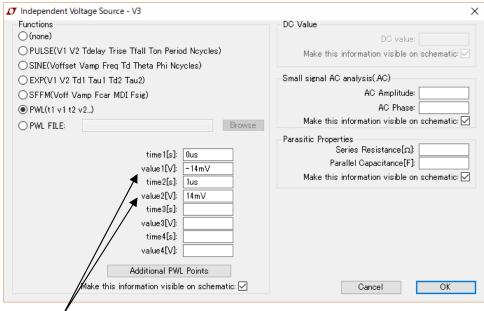
- Carry out the TRAN analysis of the clocked comparator and attach the simulation results to your report.
  - V(inp), V(inn), V(outp), V(vdn), V(vdp), and V(clk)
- Evaluate the comparison accuracy by simulation.
  - The accuracy depends on the clock frequency. Try to operate at  $f_{clk}$  = 10MHz (Tperiod = 100ns).
  - The accuracy depends on the common mode voltage too. Evaluate the comparison accuracy for VCM = -1.0V, 0.0V, and 1.0V.

#### Schematic



# Clock pulse and input voltage



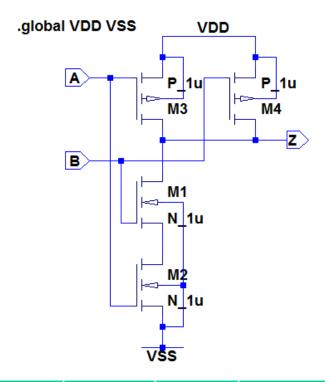


Change the Value1 and Value2 to evaluate the comparison accuracy.

# MOSFET parameters

MOSFET	L(m)	W(m)	M	AD, AS(m <sup>2</sup> )	PD, PS(m)	W/L
M1, M2	2u	10u	2	30p	16u	10
M3	4u	20u	2	60p	26u	10
M4, M5	2u	10u	6	30p	16u	30
M6	4u	20u	6	60p	26u	30
M7-M10	2u	10u	3	30p	16u	15
M11-M14	2u	10u	1	30p	16u	5

### NAND2 schematic



MOSFET	L(m)	W(m)	M	$AD, AS(m^2)$	PD, PS(m)	W/L
M1, M2	1u	5u	4	15p	11u	5
M3, M4	1u	15u	1	45p	21u	15